



Part Number:MT29F512G08EMCBBJ5-10ES:B TR

Manufacturer/Brand:Micron Technology

Product description:IC FLASH 512G PARALLEL 100MHZ

Datasheets:

RoHs Status:Lead free / RoHS Compliant

Ship From:Hong Kong

Shipment Way:DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

Image may be representation. See specifications for product details.

Specifications of MT29F512G08EMCBBJ5-10ES:B TR

PART NUMBER	MT29F512G08EMCBBJ5-10ES:B TR
MANUFACTURER	Micron Technology
DESCRIPTION	IC FLASH 512G PARALLEL 100MHZ
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DATA SHEET	
WRITE CYCLE TIME - WORD, PAGE	-
VOLTAGE - SUPPLY	2.7 V ~ 3.6 V
TECHNOLOGY	FLASH - NAND
SERIES	-
PACKAGING	Tape & Reel (TR)
OTHER NAMES	MT29F512G08EMCBBJ5-10ES:B TR-ND MT29F512G08EMCBBJ5-10ES:BTR
OPERATING TEMPERATURE	0°C ~ 70°C (TA)
MOISTURE SENSITIVITY LEVEL (MSL)	3 (168 Hours)
MEMORY TYPE	Non-Volatile
MEMORY SIZE	512Gb (64G x 8)
MEMORY INTERFACE	Parallel
MEMORY FORMAT	FLASH
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILED DESCRIPTION	FLASH - NAND Memory IC 512Gb (64G x 8) Parallel 100MHz
CLOCK FREQUENCY	100MHz

Related Tags

Micron Technology MT29F512G08EMCBBJ5-10ES:B TR	MT29F512G08EMCBBJ5-10ES:B TR Distributor	MT29F512G08EMCBBJ5-10ES:B TR Supplier
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 MT29F64G08ABEBBH6-12:B Manufacturers: Micron Technology Description: IC FLASH 64G PARALLEL 83MHZ In stock: Out stock RFQ	 MT29F64G08ABCBBH6-6:B TR Manufacturers: Micron Technology Description: IC FLASH 64G PARALLEL 167MHZ In stock: Out stock RFQ
 MT29F512G08EMCBBJ5-6:B Manufacturers: Micron Technology Description: IC FLASH 512G PARALLEL 167MHZ In stock: Out stock RFQ	 MT29F512G08EKCBJ5-6:B Manufacturers: Micron Technology Description: NAND FLASH In stock: Out stock RFQ
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 MT29F64G08ABCBBH6-6IT:B TR Manufacturers: Micron Technology Description: IC FLASH 64G PARALLEL 167MHZ In stock: Out stock RFQ	 MT29F512G08ELCDBG7-37ES:D TR Manufacturers: Micron Technology Description: IC FLASH 512G PARALLEL 267MHZ In stock: Out stock RFQ